IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

re Patent Application of: Byung Jin AHN, et al.

Serial No.: 10/750,850 Group Art Unit: 2818

Filed: January 5, 2004 Examiner: Nguyen, Dao H

For: FLASH MEMORY CELL AND METHOD OF MANUFACTURING THE SAME, AND

PROGRAMMING/ERASING/READING METHOD IN THE FLASH MEMORY CELL

TRANSMITTAL

Honorable Commissioner for Patents P.O. Box 1450

Alexandria, VA 22313-1450

December 13, 2004

Transmitted herewith is an Amendment, Petition for One Month Extension of Time and a Revocation of Power of Attorney and New Power of Attorney.

The fee has been calculated as shown below:

	Claims Remaining		Highest Number	Present Extra	Small Entit	y Other Than A Small Entity
	After		Previously	7	Rate Addit.	(or) Rate Addit.
	Amendment		Paid For		Fee	Fee ·
Total	08	-	20=	0	x 09 = \$	x 18 = \$
Indep	. 01	-	03=	0	x 42 = \$	x 84 = \$
First Presentation of Multiple Dependent Claims $+140 \Rightarrow \$$ $+280 = \$$						+ 280 = \$
Total Additional Fee \$						\$

XXXX A check in the amount of \$120.00 is attached for Petition for One Month Extension of Time.

XXXX If a Petition for Extension of Time is necessary and the Petition and/or the check is not enclosed, this will act as the Petition and applicant herewith petitions the Commissioner to extend the time for response and charge any fees necessary under 37 CFR 1.17 (a)(1)-(5) to Deposit Account No. 50-3226. The Commissioner is also authorized to charge payment of any other additional fees associated with this communication or credit any overpayment to Deposit Account No. 50-3226. A duplicate copy of this sheet is attached.

Respectfully submitted,

Piper Rudnick, LLP

Yoon S. Ham

Req. No. 45,307

P.O. Box 9271 Reston, VA 20195

Telephone: (202) 861-3871 Atty. Docket: 312971-P0026

YSH:jr



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* * * * * * * * * *

AMENDMENT

Honorable Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

December 13, 2004

Sir:

DEC 1 3 2004

In response to the outstanding Official Action dated August 12, 2004, please amend the subject application as follows: